

P-Channel -40V (D-S) Power MOSFET

Features

- 100% Avalanche Tested
- Extremely Low Losses with Low FOM Rdson*Qg
- Halogen Free, Pb-Free
- RoHS Compliant

Applications

- DC/DC
- Motors, lamps
- Power switching

Absolute Maximum Ratings (TJ=25°C unless otherwise noted)						
Parameter	Symbol	Value	Unit			
Drain Source Voltage	V _{DS}	-40	V			
Gate Source Voltage	V _{GS}	±20	V			
Drain Current, Continuous	T _C =25°C	-		٥		
V _{GS} =10V(<i>Note 1</i>)	T _c =100°C	· I _D	-23	A		
Drain Current, Pulsed (Note 2)	I _{DM}	-120	А			
Single Avalanche Energy @ L=0.1mH	E _{AS}	E _{AS} 125				
Power Dissipation(<i>Note 3</i>) T _C =25°C		PD	25	W		
Operating Junction/ Storage Tempera	TJ/ T _{STG}	-55 to +150	°C			

Note 1: Calculated continuous current based on maximum allowable junction temperature. Note 2: Repetitive rating; pulse width limited by max. junction temperature.

Thermal Characteristics	al Characteristics					
Parameter	Symbol	Мах	Unit			
Thermal Resistance Junction to Case(Note 3)	R _{thJC}	5	°C/W			
Thermal Resistance Junction to Ambient (Note 4)	RthJA	62	°C/W			

Note 3: The power dissipation PD is based on max. junction temperature, using junction-to-case thermal resistance. Note 4: The value of R_{0JA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with TA =25 ℃.





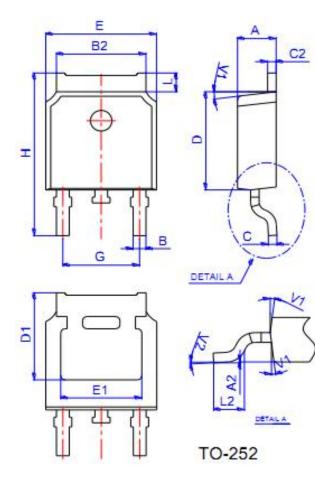
Electrical Characteristics (T _J = 25°C unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Drain Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250µA	-40			V	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-40V, V _{GS} =0V			-1	uA	
Gate Threshold Voltage	V _{GS(TH)}	$V_{DS}=V_{GS}$, $I_{DS}=-250$ uA	-1		-2.5	V	
Gate Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$			±100	nA	
Drain-Source On-state	_	V _{GS} =-10V, I _D =-30A		15	18		
Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-20A		18	25	V uA V	
Total Gate Charge	Qg			25		nC	
Gate Source Charge	Q _{gs}	I _D = -12A, V _{DS} =-20V, V _{GS} = -4.5V		11			
Gate Drain Charge	Q _{gd}	$V_{GS} = -4.5V$		9.5			
Turn-on Delay Time	t _{d(on)}			47			
Turn-on Rise Time	tr	V _{GS} =-10V, V _{DD} =-15V,		23		- ns	
Turn-off Delay Time	t _{d(off)}	R _L =15Ω, R _{GEN} =6Ω, I _D = -1A		86			
Turn-off Fall Time	tr			9.2			
Input Capacitance	Ciss			2760			
Output Capacitance	Coss	V _{GS=} 0V, V _{DS} =-20V, f=1MHz		259		pF	
Reverse Transfer Capacitance	Crss			83			

Reverse Diode Characte	eristics	(T」=25°C unless otherwise noted)				ax Unit		
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Continuous Source Current	I _{SD}	T _c =25°C			-40	А		
Pulsed Source Current	I _{SM}	T _c =25°C			-90	А		
Diode Forward Voltage	V _{SD}	I _F =-1A, V _{GS} =0V			-1.3	V		



Package Outline Dimensions (Unit: millimeters)

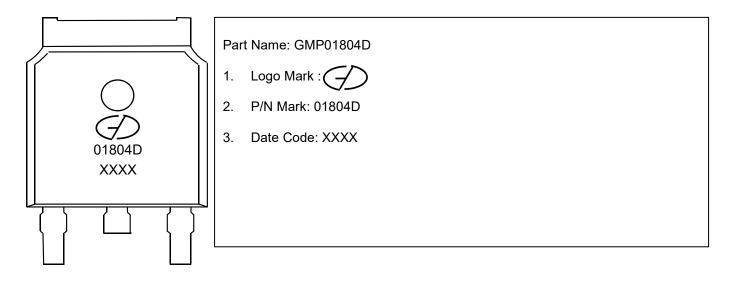
TO-252



Ref.	Dimensions						
	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	2.10		2.50	0.083		0.098	
A2	0		0.10	0		0.004	
В	0.66		0.86	0.026		0.034	
B2	5.18		5.48	0.202		0.216	
С	0.40		0.60	0.016		0.024	
C2	0.44		0.58	0.017		0.023	
D	5.90		6.30	0.232		0.248	
D1	5.30REF			0.209REF			
E	6.40		6.80	0.252		0.268	
E1	4.63			0.182			
G	4.47		4.67	0.176		0.184	
н	9.50		10.70	0.374		0.421	
L	1.09		1.21	0.043		0.048	
L2	1.35		1.65	0.053		0.065	
V1		7°			7°		
V2	0°		6°	0°		6°	



Marking Outline





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